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FAIRCHILD

SEMICONDUCTOR®

FMG2G400US60

Molding Type Module

General Description

Fairchild IGBT Power Module provides low conduction and switching losses as well as short circuit ruggedness. It's designed for the applications such as motor control, uninterrupted power supplies (UPS) and general inverters where short-circuit ruggedness is required.

Features

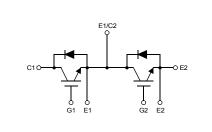
- Short Circuit Rated Time; 10us @ T_C =100°C, V_{GE} = 15V
- High Speed Switching
- Low Saturation Voltage : V_{CE}(sat) = 2.1 V @ I_C = 400A
- High Input Impedance
- Fast & Soft Anti-Parallel FWD
- UL Certified No.E209204

Application

- AC & DC Motor Controls
- General Purpose Inverters
- Robotics
- Servo Controls
- UPS



Package Code : 7PM-IA



Internal Circuit Diagram

Absolute Maximum Ratings T_c = 25°C unless otherwise noted

Symbol	Description		FMG2G400US60	Units
V _{CES}	Collector-Emitter Voltage		600	V
V _{GES}	Gate-Emitter Voltage		± 20	V
I _C	Collector Current	@ T _C = 80°C	400	А
I _{CM (1)}	Pulsed Collector Current		800	А
l _F	Diode Continuous Forward Current	@ T _C = 80°C	400	А
I _{FM}	Diode Maximum Forward Current		800	А
P _D	Maximum Power Dissipation	@ T _C = 25°C	1136	W
T _{SC}	Short Circuit Withstand Time	@ T _C = 100°C	10	US
TJ	Operating Junction Temperature		-40 to +150	°C
T _{STG}	Storage Temperature Range		-40 to +125	°C
V _{ISO}	Isolation Voltage	@ AC 1minute	2500	V
Mounting Torque	Power Terminal Screw : M6		4.0	N.m
Mounting Torque	Mounting Screw : M6		4.0	N.m

Notes :

(1) Repetitive rating : Pulse width limited by max. junction temperature

FMG2G400US60

IGBT

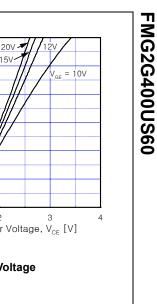
Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Units
Off Cha	racteristics					
BV _{CES}	Collector-Emitter Breakdown Voltage	V _{GE} = 0V, I _C = 250uA	600			V
ΔB _{VCES} / ΔT _J	Temperature Coeff. of Breakdown Voltage	V _{GE} = 0V, I _C = 1mA		0.6		V/°C
I _{CES}	Collector Cut-Off Current	$V_{CE} = V_{CES}, V_{GE} = 0V$			250	uA
I _{GES}	Gate - Emitter Leakage Current	$V_{GE} = V_{GES}, V_{CE} = 0V$			± 100	nA
	racteristics		5.0	6.5	8.5	V
V _{GE(th)} V _{CE(sat)}	Gate - Emitter Threshold Voltage Collector to Emitter Saturation Voltage	$I_{C} = 400$ mA, $V_{CE} = V_{GE}$ $I_{C} = 400$ A, $V_{GE} = 15V$	5.0	0.5 2.1	8.5 2.7	V
• • • • • •						
Switchi	ng Characteristics					
	Turn-On Delay Time			160		ns
t _{d(on)}		V = 200 V L = 400 A		160 220		ns ns
t _{d(on)} t _r	Turn-On Delay Time	$V_{CC} = 300 \text{ V}, \text{ I}_{C} = 400 \text{ A},$				-
t _{d(on)} t _r t _{d(off)}	Turn-On Delay Time Rise Time	$R_{G} = 2\Omega, V_{GE} = 15V,$		220		ns
t _{d(on)} t _r t _{d(off)} t _f E _{on}	Turn-On Delay Time Rise Time Turn-Off Delay Time			220 230		ns ns
t _{d(on)} t _r t _{d(off)} t _f E _{on}	Turn-On Delay Time Rise Time Turn-Off Delay Time Fall Time	$R_{G} = 2\Omega, V_{GE} = 15V,$		220 230 150		ns ns ns
t _{d(on)} t _r t _{d(off)} t _f E _{on} E _{off}	Turn-On Delay Time Rise Time Turn-Off Delay Time Fall Time Turn-On Switching Loss	$R_{G} = 2\Omega, V_{GE} = 15V,$		220 230 150 9.5		ns ns ns mJ
$\begin{array}{c} t_{d(on)} \\ t_r \\ t_{d(off)} \\ t_{f} \\ E_{on} \\ E_{off} \\ t_{d(on)} \end{array}$	Turn-On Delay Time Rise Time Turn-Off Delay Time Fall Time Turn-On Switching Loss Turn-Off Switching Loss	$R_G = 2\Omega$, $V_{GE} = 15V$, Inductive Load, $T_C = 25^{\circ}C$	 	220 230 150 9.5 21	 250 	ns ns ns mJ mJ
t _{d(on)} t _r t _{d(off)} t _f E _{on} E _{off} t _{d(on)} t _r	Turn-On Delay Time Rise Time Turn-Off Delay Time Fall Time Turn-On Switching Loss Turn-Off Switching Loss Turn-On Delay Time	$R_G = 2\Omega$, $V_{GE} = 15V$, Inductive Load, $T_C = 25^{\circ}C$ $V_{CC} = 300$ V, $I_C = 400A$,	 	220 230 150 9.5 21 320	 250 	ns ns mJ mJ ns
$\begin{array}{c} t_{d(on)} \\ \hline t_r \\ \hline t_{d(off)} \\ \hline t_{f} \\ \hline E_{on} \\ \hline E_{off} \\ \hline t_{d(on)} \\ \hline t_r \\ \hline t_{d(off)} \\ \hline \end{array}$	Turn-On Delay Time Rise Time Turn-Off Delay Time Fall Time Turn-On Switching Loss Turn-Off Switching Loss Turn-On Delay Time Rise Time	$R_{G} = 2\Omega, V_{GE} = 15V,$ Inductive Load, $T_{C} = 25^{\circ}C$ $V_{CC} = 300 V, I_{C} = 400A,$ $R_{G} = 2\Omega, V_{GE} = 15V,$	 	220 230 150 9.5 21 320 240	 250 	ns ns mJ mJ ns ns
$\begin{array}{c} t_{d(on)} \\ \hline t_r \\ \hline t_d(off) \\ \hline t_f \\ \hline E_{on} \\ \hline E_{off} \\ \hline t_{d(on)} \\ \hline t_r \\ \hline t_d(off) \\ \hline t_f \\ \hline \end{array}$	Turn-On Delay Time Rise Time Turn-Off Delay Time Fall Time Turn-On Switching Loss Turn-Off Switching Loss Turn-On Delay Time Rise Time Turn-Off Delay Time	$R_G = 2\Omega$, $V_{GE} = 15V$, Inductive Load, $T_C = 25^{\circ}C$ $V_{CC} = 300$ V, $I_C = 400A$,	 	220 230 150 9.5 21 320 240 290	 250 	ns ns mJ mJ ns ns ns
t _{d(on)} t _r t _d (off) E _{on} E _{off} t _{d(on)} t _r t _{d(off)} t _f E _{on}	Turn-On Delay Time Rise Time Turn-Off Delay Time Fall Time Turn-On Switching Loss Turn-Off Switching Loss Turn-On Delay Time Rise Time Turn-Off Delay Time Fall Time Turn-Off Delay Time Fall Time	$R_{G} = 2\Omega, V_{GE} = 15V,$ Inductive Load, $T_{C} = 25^{\circ}C$ $V_{CC} = 300 V, I_{C} = 400A,$ $R_{G} = 2\Omega, V_{GE} = 15V,$ Inductive Load, $T_{C} = 125^{\circ}C$	 	220 230 150 9.5 21 320 240 290 230	 250 	ns ns mJ mJ ns ns ns ns
t _{d(on)} t _r t _{d(off)} t _f Eon Eoff t _{d(on)} t _r t _{d(off)} t _f Eon Eoff	Turn-On Delay Time Rise Time Turn-Off Delay Time Fall Time Turn-On Switching Loss Turn-Off Switching Loss Turn-On Delay Time Rise Time Turn-Off Delay Time Fall Time Turn-On Switching Loss	$R_{G} = 2\Omega, V_{GE} = 15V,$ Inductive Load, $T_{C} = 25^{\circ}C$ $V_{CC} = 300 V, I_{C} = 400A,$ $R_{G} = 2\Omega, V_{GE} = 15V,$	 	220 230 150 9.5 21 320 240 290 230 11	 250 	ns ns mJ mJ ns ns ns ns ns mJ
$\begin{array}{c} \frac{t_{d(on)}}{t_{r}} \\ \hline t_{r} \\ \hline t_{d(off)} \\ \hline E_{off} \\ \hline E_{off} \\ \hline t_{d(on)} \\ \hline t_{r} \\ \hline t_{d(off)} \\ \hline t_{f} \\ \hline E_{on} \\ \hline E_{off} \\ \hline T_{sc} \\ \end{array}$	Turn-On Delay Time Rise Time Turn-Off Delay Time Fall Time Turn-On Switching Loss Turn-Off Switching Loss Turn-Off Switching Loss Turn-On Delay Time Rise Time Turn-Off Delay Time Fall Time Turn-Off Delay Time Fall Time Turn-On Switching Loss Turn-Off Switching Loss	$R_{G} = 2\Omega, V_{GE} = 15V,$ Inductive Load, $T_{C} = 25^{\circ}C$ $V_{CC} = 300 \text{ V}, I_{C} = 400\text{ A},$ $R_{G} = 2\Omega, V_{GE} = 15V,$ Inductive Load, $T_{C} = 125^{\circ}C$ $V_{CC} = 300 \text{ V}, V_{GE} = 15V$ @ $T_{C} = 100^{\circ}C$	 	220 230 150 9.5 21 320 240 290 230 11 26	 250 	ns ns mJ mJ ns ns ns ns mJ mJ
$\begin{array}{c} {\rm Switchil} \\ {\rm t}_{d(on)} \\ {\rm t}_{r} \\ {\rm t}_{d(off)} \\ {\rm t}_{f} \\ {\rm E}_{on} \\ {\rm E}_{off} \\ {\rm t}_{d(on)} \\ {\rm t}_{r} \\ {\rm t}_{d(off)} \\ {\rm t}_{f} \\ {\rm E}_{on} \\ {\rm E}_{off} \\ {\rm T}_{sc} \\ {\rm Q}_{g} \\ {\rm Q}_{gc} \\ {\rm Q}_{gc} \\ \end{array}$	Turn-On Delay Time Rise Time Turn-Off Delay Time Fall Time Turn-On Switching Loss Turn-Off Switching Loss Turn-On Delay Time Rise Time Turn-Off Delay Time Fall Time Turn-Off Delay Time Fall Time Turn-On Switching Loss Turn-Off Delay Time Fall Time Turn-Off Switching Loss Short Circuit Withstand Time	$R_{G} = 2\Omega, V_{GE} = 15V,$ Inductive Load, $T_{C} = 25^{\circ}C$ $V_{CC} = 300 V, I_{C} = 400A,$ $R_{G} = 2\Omega, V_{GE} = 15V,$ Inductive Load, $T_{C} = 125^{\circ}C$	 10	220 230 150 9.5 21 320 240 290 230 11 26 	 250 	ns ns mJ mJ mJ ns ns ns ms mJ mJ us

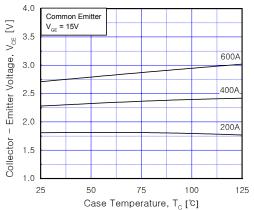
Electrical Characteristics of DIODE $T_{C} = 25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Test Conditions		Min.	Тур.	Max.	Units
V	Diodo Eonward Voltago	L = 400A	$T_{C} = 25^{\circ}C$		1.9	2.8	v
V _{FM}	Diode Forward Voltage	I _F = 400A	T _C = 100°C		1.8		v
	Diede Deverse Desever Time		$T_{\rm C}$ = 25°C		90	130	
t _{rr}	Diode Reverse Recovery Time		T _C = 100°C		130		ns
1	Diode Peak Reverse Recovery	I _F = 400A	$T_{\rm C} = 25^{\circ}{\rm C}$		35	46	А
Irr	Current	di / dt = 800 A/us	T _C = 100°C		76		A
0	Diede Deverse Desevery Charge	harge	$T_{\rm C} = 25^{\circ}{\rm C}$		1580	3000	
Q _{rr}	Diode Reverse Recovery Charge		T _C = 100°C		4940		nC

Thermal Characteristics

Symbol	Parameter	Тур.	Max.	Units
$R_{\theta JC}$	Junction-to-Case (IGBT Part, per 1/2 Module)		0.11	°C/W
$R_{\theta JC}$	Junction-to-Case (DIODE Part, per 1/2 Module)		0.18	°C/W
$R_{\theta JC}$	Case-to-Sink (Conductive grease applied)	0.03		°C/W
Weight	Weight of Module	360		g





600

500

400

300

200

100

0

0

1

Characteristics

Collector Current, I_c [A]

10

12V

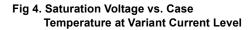
 $V_{GE} = 10V$

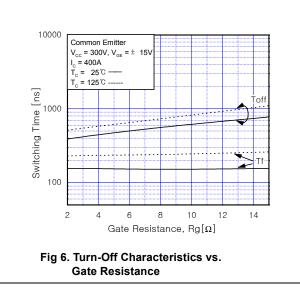
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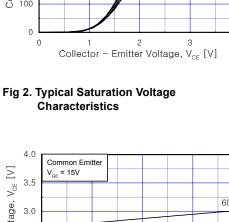
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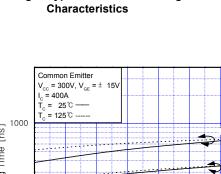
Common Emitter

T_c = 25℃









Switching Time [ns] 100 6 8 10 12 14 2 4 Gate Resistance, $Rg[\Omega]$ Fig 5. Turn-On Characteristics vs. **Gate Resistance**

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600

500

Collector Current, I_o [A] 00 000 000 100 000 000

0

600

500

400

300

200

100

0

0

Collector Current, I_c [A]

Common Emitter T_c = 125°C

Common Emitter

= 125°C •••••

1

Collector - Emitter Voltage, V_{CE} [V]

20V-

15V[.]

2

Collector – Emitter Voltage, V_{CE} [V]

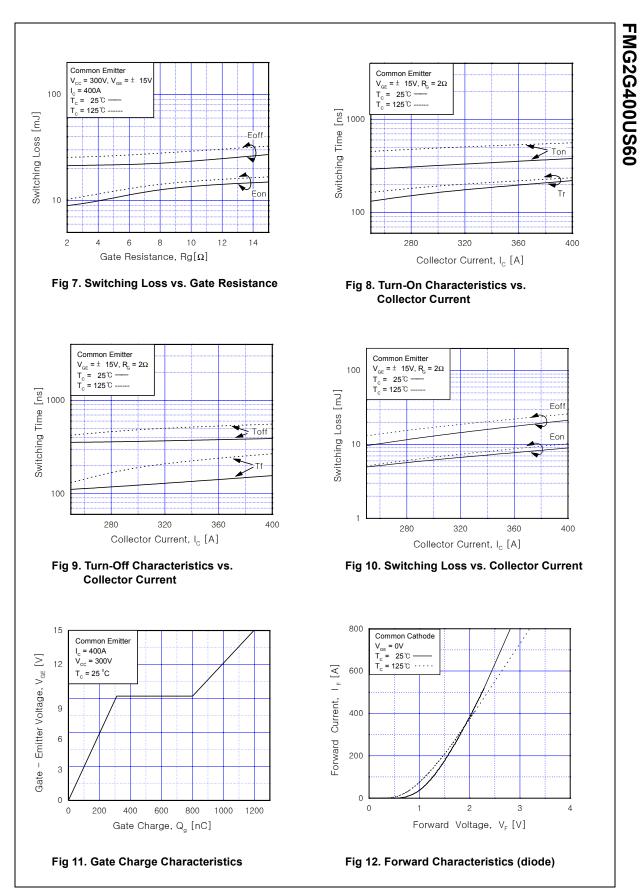
1

Fig 3. Typical Saturation Voltage

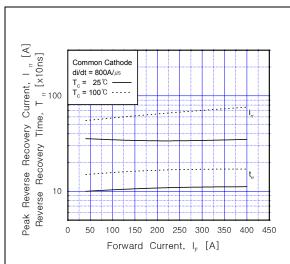
Fig 1. Typical Output Characteristics

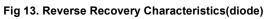
= 15V ٧_,

= 25°C T_c



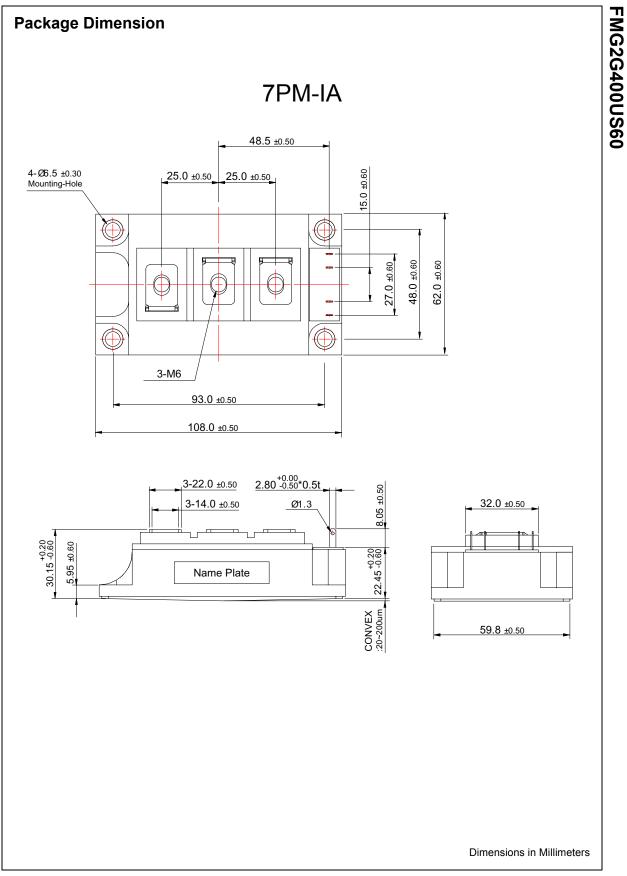
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CoolFET™	FASTr™	MicroFET™	PowerTrench [®]	SuperSOT™-6
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